

L Number	Hits	Search Text	DB	Time stamp
2	15468	soi or (silicon near2 insulator)	USPAT; US-PGPUB	2003/05/18 20:25
3	265	silicon near2 boat	USPAT; US-PGPUB	2003/05/18 20:25
4	14	((soi or (silicon near2 insulator)) and (silicon near2 boat))	USPAT; US-PGPUB	2003/05/18 20:26
5	13	((soi or (silicon near2 insulator)) and (silicon near2 boat)) and @ad<20020307	USPAT; US-PGPUB	2003/05/18 20:27
-	34	silicon adj boat	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/20 18:41
-	34	silicon adj boat	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/20 11:08
-	60174	silicon adj carbide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/20 18:18
-	92082	cvd	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/20 18:18
-	2120	((silicon adj carbide) same cvd)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/20 18:18
-	66246	boat	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/20 18:18
-	41	((silicon adj carbide) same cvd) same boat	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/20 18:18
-	34	silicon adj boat	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/21 19:44
-	1	((silicon adj carbide) same cvd) same boat) and (silicon adj boat)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/20 18:43
-	74	((silicon adj carbide) same cvd) same boat) or (silicon adj boat)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/20 18:43
-	14400	soi	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/21 19:43
-	34	silicon adj boat	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/21 19:44

-	1	soi same (silicon adj boat)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/21 19:46
-	1146922	semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/21 19:50
-	5	(silicon adj boat) same semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/21 19:46
-	12	semiconductor adj on adj insulat\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/21 19:56
-	14562	soi	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 11:04
-	508529	transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 11:04
-	3801	soi same transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 11:04
-	60532	silicon adj carbide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 11:04
-	10	(soi same transistor) same (silicon adj carbide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 11:05